

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant	:	Hannu Huotari
Appl. No.	:	10/601,037
Filed	:	June 19, 2003
For	:	METHOD TO FABRICATE DUAL METAL CMOS DEVICES
Examiner	:	Christy L. Novacek
Group Art Unit:	:	2822

**COMMENTS ON STATEMENT OF REASONS FOR ALLOWANCE**


Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

This communication is submitted in response to the Notice of Allowability dated June 23, 2006. In discussing the Reasons for Allowance, the Examiner refers generally to certain features of independent Claims 15 and 42. Each of the claims recites different patentable combinations of features and elements. To the extent that the Examiner's paraphrasing of the subject matter of particular independent claims differs from the language of the allowed claims, Applicants respectfully disagree with the Reasons for Allowance.

Respectfully submitted,  
KNOBBE, MARTENS, OLSON & BEAR, LLP

Dated: August 31, 2006

By:   
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